P-Channel 100 V (D-S) MOSFET

| PRODUCT SUMMARY | | | | | |
|---------------------|---|-------------------------------|------|--|--|
| V _{DS} (V) | $R_{DS(on)}(\Omega)$ | $R_{DS(on)}(\Omega)$ $I_D(A)$ | | | |
| - 100 | $0.195 \text{ at V}_{GS} = -10 \text{ V}$ | - 19 | 11.7 | | |
| - 100 | 0.210 at V _{GS} = - 4.5 V | - 17 | 11.7 | | |

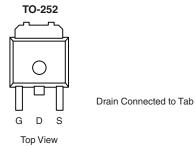
FEATURES

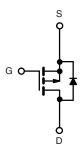
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- 100 % R_q and UIS Tested
- Compliant to RoHS Directive 2002/95/EC



APPLICATIONS

- · Power Switch
- DC/DC Converters





P-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS T _C = 25 °C, unless otherwise noted | | | | | |
|---|-------------------------------------|-----------------------------------|-------------------|------|--|
| Parameter | | Symbol | Limit | Unit | |
| Drain-Source Voltage | V _{DS} | - 100 | | | |
| Gate-Source Voltage | V _{GS} | ± 20 | V | | |
| Continuous Drain Current (T _{.I} = 150 °C) | T _C = 25 °C | l- | - 19 | _ | |
| Continuous Diam Current (1) = 150 °C) | T _C = 70 °C | - I _D | - 12.1 | | |
| Pulsed Drain Current | | I _{DM} | - 45 | А | |
| Avalanche Current | | I _{AS} | - 18 | | |
| Single Avalanche Energy ^a | L = 0.1 mH | E _{AS} | 16.2 | mJ | |
| M | T _C = 25 °C | В | 32.1 ^b | W | |
| Maximum Power Dissipation ^a | T _A = 25 °C ^c | - P _D | 2.5 | | |
| Operating Junction and Storage Temperature R | ange | T _J , T _{stg} | - 55 to 150 | °C | |

| THERMAL RESISTANCE RATINGS | | | | | | |
|--|-------------------|-------|------|--|--|--|
| Parameter | Symbol | Limit | Unit | | | |
| Junction-to-Ambient (PCB Mount) ^c | R _{thJA} | 50 | °C/W | | | |
| Junction-to-Case (Drain) | R _{thJC} | 3.9 | C/VV | | | |

Notes:

- a. Duty cycle \leq 1 %.
- b. See SOA curve for voltage derating.
- c. When Mounted on 1" square PCB (FR-4 material).



| Parameter | Symbol | Test Conditions | Min. | Тур. | Max. | Unit | |
|---|----------------------|--|------|-------|-------|------|--|
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | V _{DS} | V_{DS} $V_{DS} = 0 \text{ V, } I_{D} = -250 \mu\text{A}$ | | | | V | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_{D} = -250 \mu A$ | - 1 | | - 2.5 | V | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$ | | | ± 250 | nA | |
| | | V _{DS} = - 100 V, V _{GS} = 0 V | | | - 1 | | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} = - 100 V, V _{GS} = 0 V, T _J = 125 °C | | | - 50 | μΑ | |
| | | V _{DS} = - 100 V, V _{GS} = 0 V, T _J = 150 °C | | | - 250 | 1 | |
| On-State Drain Current ^a | I _{D(on)} | $V_{DS} \le -10 \text{ V}, V_{GS} = -10 \text{ V}$ | - 15 | | | Α | |
| | Ь | V _{GS} = - 10 V, I _D = - 3.6 A | | 0.162 | 0.195 | Ω | |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | V _{GS} = - 4.5 V, I _D = - 3.4 A | | 0.175 | 0.210 | | |
| Forward Transconductance ^a | 9 _{fs} | V _{DS} = - 15 V, I _D = - 3.6 A | | 12 | | S | |
| Dynamic ^b | | | | • | | | |
| Input Capacitance | C _{iss} | | | 1055 | | pF | |
| Output Capacitance | C _{oss} | V _{GS} = 0 V, V _{DS} = - 50 V, f = 1 MHz | | 65 | | | |
| Reverse Transfer Capacitance | C _{rss} | 1 | | 41 | | | |
| Tatal Cata Chausa C | | V _{DS} = - 50 V, V _{GS} = - 10 V, I _D = - 3.6 A | | 23.2 | 34.8 | nC | |
| Total Gate Charge ^c | | | | 11.7 | 17.6 | | |
| Gate-Source Charge ^c | Q_{gs} | $V_{DS} = -50 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -3.6 \text{ A}$ | | 3.5 | | | |
| Gate-Drain Charge ^c | Q_{gd} | | | 4.8 | | | |
| Gate Resistance | R_g | f = 1 MHz | 1.2 | 5.7 | 11.5 | Ω | |
| Turn-On Delay Time ^c | t _{d(on)} | | | 7 | 14 | | |
| Rise Time ^c | t _r | $V_{DD} = -50 \text{ V}, R_L = 17.2 \Omega$ | | 12 | 18 | 20 | |
| Turn-Off Delay Time ^c | t _{d(off)} | $I_D \cong$ - 2.9 A, V_{GEN} = - 10 V, R_g = 1 Ω | | 33 | 50 | ns | |
| Fall Time ^c | t _f |] | | 9 | 18 | | |
| Drain-Source Body Diode Ratings at | nd Characteri | stics T _C = 25 °C ^b | | | | | |
| Continuous Current | I _S | | | | - 19 | ^ | |
| Pulsed Current | I _{SM} | | | | - 45 | Α | |
| Forward Voltage ^a | V _{SD} | I _F = - 2.9 A, V _{GS} = 0 V | | - 0.8 | - 1.5 | V | |
| Reverse Recovery Time | t _{rr} | | | 50 | 75 | ns | |
| Peak Reverse Recovery Current | I _{RM(REC)} | I _F = - 2.9 A, dl/dt = 100 A/μs | | - 4 | - 6 | Α | |
| Reverse Recovery Charge | Q _{rr} | 1 | | 98 | 147 | nC | |

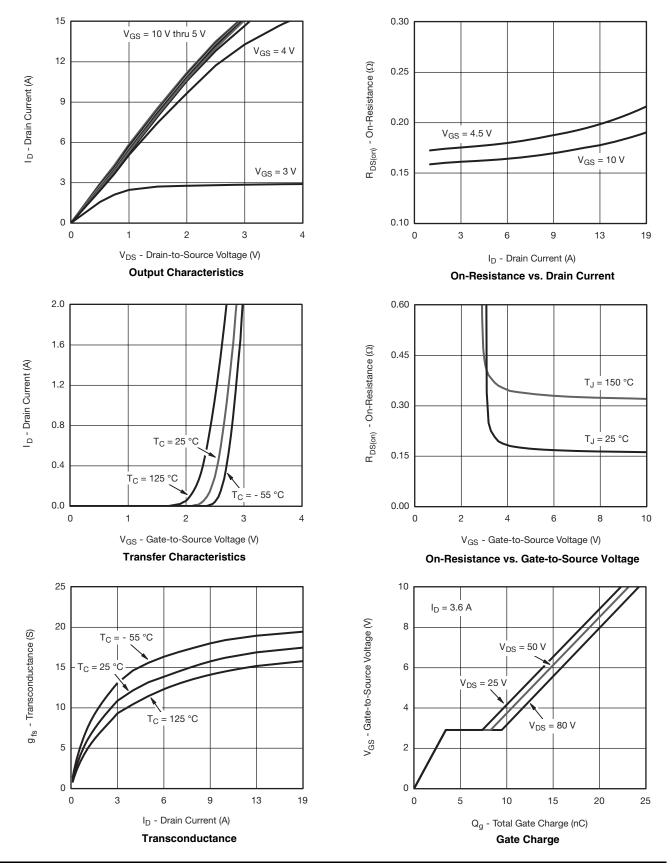
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

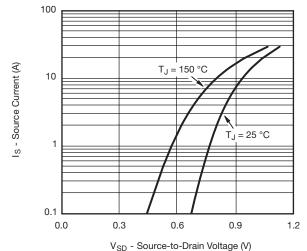


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

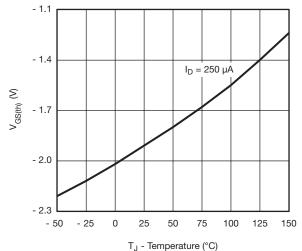




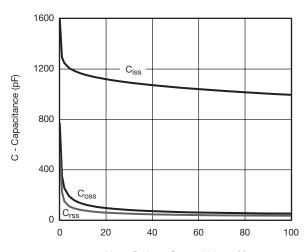
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



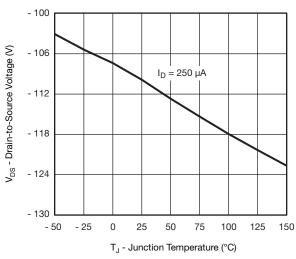
Source-Drain Diode Forward Voltage



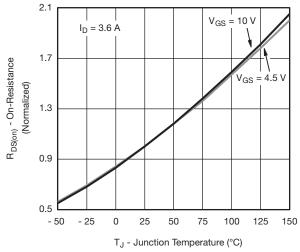
Threshold Voltage



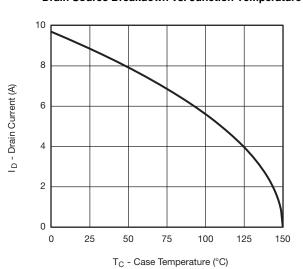
 V_{DS} - Drain-to-Source Voltage (V) $\label{eq:capacitance}$



Drain Source Breakdown vs. Junction Temperature



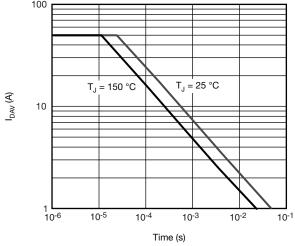
On-Resistance vs. Junction Temperature

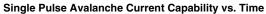


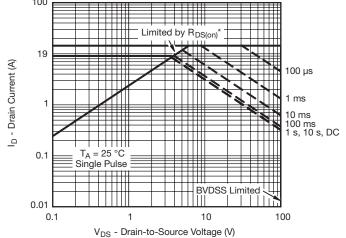
Current Derating



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

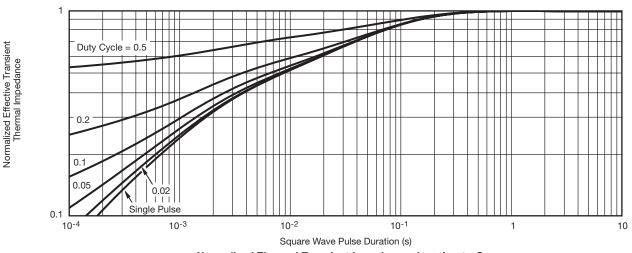






* $V_{GS} > \mbox{minimum} \ V_{GS}$ at which $R_{DS(on)}$ is specified

Safe Operating Area

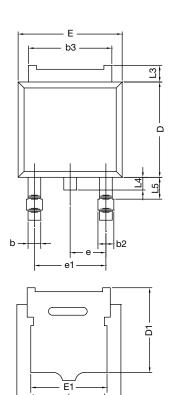


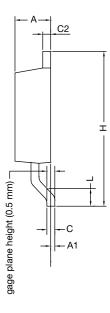
Normalized Thermal Transient Impedance, Junction-to-Case





TO-252AA CASE OUTLINE





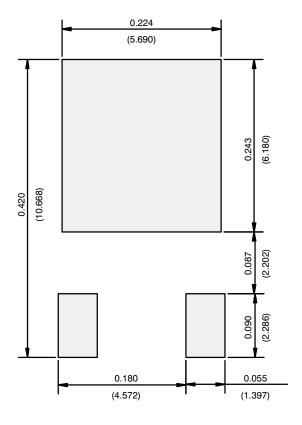
| | MILLIMETERS | | INCHES | | |
|---------------------------------|-------------|-------|-----------|-------|--|
| DIM. | MIN. | MAX. | MIN. | MAX. | |
| А | 2.18 | 2.38 | 0.086 | 0.094 | |
| A1 | - | 0.127 | - | 0.005 | |
| b | 0.64 | 0.88 | 0.025 | 0.035 | |
| b2 | 0.76 | 1.14 | 0.030 | 0.045 | |
| b3 | 4.95 | 5.46 | 0.195 | 0.215 | |
| С | 0.46 | 0.61 | 0.018 | 0.024 | |
| C2 | 0.46 | 0.89 | 0.018 | 0.035 | |
| D | 5.97 | 6.22 | 0.235 | 0.245 | |
| D1 | 5.21 | - | 0.205 | - | |
| Е | 6.35 | 6.73 | 0.250 | 0.265 | |
| E1 | 4.32 | - | 0.170 | - | |
| Н | 9.40 | 10.41 | 0.370 | 0.410 | |
| е | 2.28 BSC | | 0.090 BSC | | |
| e1 | 4.56 | BSC | 0.180 BSC | | |
| L | 1.40 | 1.78 | 0.055 | 0.070 | |
| L3 | 0.89 | 1.27 | 0.035 | 0.050 | |
| L4 | - | 1.02 | - | 0.040 | |
| L5 | 1.14 | 1.52 | 0.045 | 0.060 | |
| ECN: X12-0247-Rev. M, 24-Dec-12 | | | | | |

DWG: 5347 Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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